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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

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LN78

GaAlAs Infrared Light Emitting Diode

For optical control systems

■ Features

- High-power output, high-efficiency: $P_O = 10 \text{ mW (typ.)}$
- High-speed modulation capability: $f_C = 12 \text{ MHz}$

■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter	Symbol	Rating	Unit	
Power dissipation	P_{D}	180	mW	
Forward current	I_{F}	100	mA	
Pulse forward current *	I _{FP}	1.0	A	
Reverse voltage	V _R	3	V	
Operating ambient temperature	Topr	-25 to +85	°C	
Storage temperature	T _{stg}	-30 to +100	°C	

Note) *: f = 100 Hz, Duty cycle = 0.1%

■ Electro-Optical Characteristics $T_a = 25$ °C±3°C

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Radiant power	Po	$I_F = 50 \text{ mA}$	6	10	1.0	mW
Reverse current	I_R	$V_R = 3 V$	2	info	10	μΑ
Forward voltage	$V_{\rm F}$	$I_F = 100 \text{ mA}$	S ×6	1.5	1.8	V
Peak emission wavelength	$\lambda_{ m P}$	$I_F = 50 \text{ mA}$	11/00	880		nm
Spectral half band width	Δλ	$I_F = 50 \text{ mA}$	30, 50	50		nm
Terminal capacitance	C_{t}	$V_R = 0 \text{ V}, f = 1 \text{ MHz}$	3/10	50		pF
Half-power angle	θ	The angle when the radiant power is halved.	15	40		0

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 measuring methods for diodes.

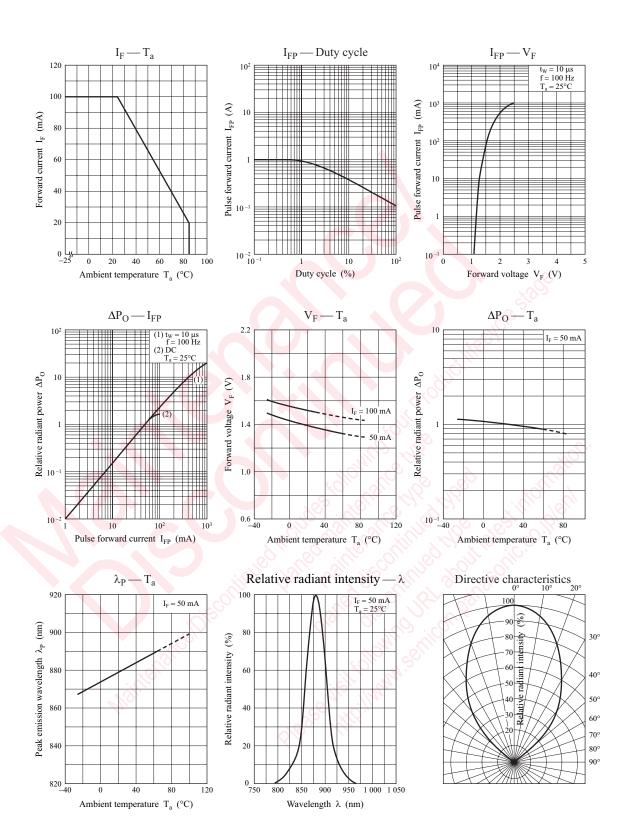
2. Modulation total power output 3 dB frequency to fall from 1 MHz.

Cutoff frequency: 12 MHz

$$f_C: 10 \times log \frac{P_O \text{ at } f = f_C}{P_O \text{ at } f = 1 \text{ MHz}} = -3$$

3. *: A light detection element uses a silicon diode have proofread a load with a standard device.

LN78 Panasonic

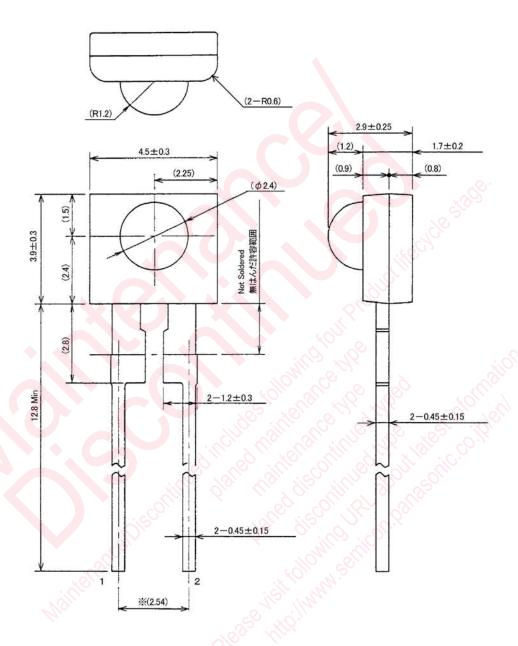


2 SHC00024DED

Panasonic LN78

■ Package (Unit: mm)

LETLSN2S0003



- Pin name
 - 1: Cathode
 - 2: Anode

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